



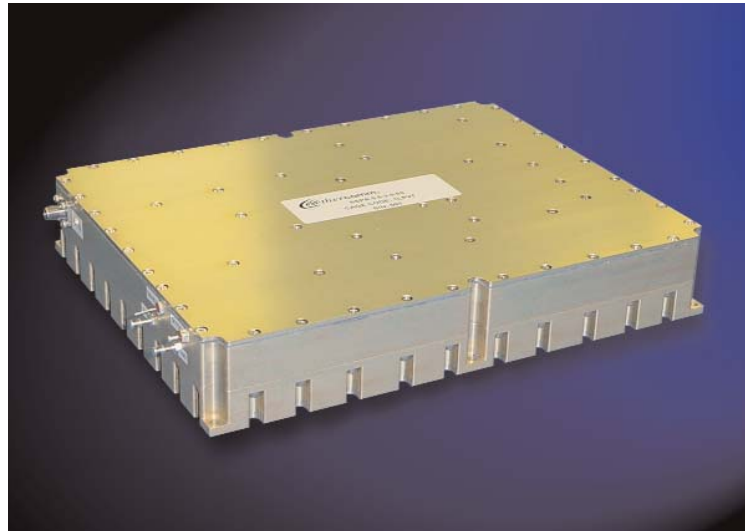
GaN Broadband Power Amplifier

Solid State RF Amplifier

Aethercomm Model Number SSPA 0.5-3.0-50 is a high power, broadband, Gallium Nitride (GaN) RF amplifier that operates from 500 MHz to 3.0 GHz. This PA is ideal for broadband military platforms as well as commercial applications because it is robust and offers high power over a multi-octave bandwidth. This amplifier was designed for broad band jamming and communication systems platforms. This amplifier operates with a base plate temperature of 85C with no degradation in the MTBF for the GaN devices inside. The RF line up is comprised of all GaN devices. It is packaged in a modular housing that is approximately 7.0" (width) by 9.0" (long) by 1.5" (height). This amplifier has a minimum P3dB of 50 watts at room temperature. Output power is typically 70 to 100 watts across the band. Noise figure at room temperature is 10.0 dB typical. This amplifier offers a typical gain of 35 dB with a typical gain flatness of ± 2.0 dB. The power and gain flatness across the band is extremely flat for the bandwidth. Input and Output VSWR is 2.0:1 maximum. Class AB quiescent current is ~5.0 amps typical employing a +50 Vdc supply. This PA operates from a +50 Vdc input voltage. Typical harmonic values can be found on the next page of this data sheet.

This SSPA includes an external DC blanking command that enables and disables the module in 5000 nSec typical. Standard features include over/under voltage protection and reverse polarity protection. The output is fully protected from an open or short circuit presented to this port with no damage. Input/output RF connectors are SMA female. Other connector types can be configured for airborne applications. DC and command voltages are accessible via DC feed through capacitors. Contact the factory with any questions you may

- **Gallium Nitride Broadband Power Amplifier**
- **Operation from 500 MHz to 3.0 GHz min**
- **Small Signal Gain 35 dB typical**
- **High Speed DC Blanking of 5uSecs max**
- **70 to 100 Watts P3dB typical**



have. This amplifier operates from -40C to +85C base plate. Summary test data is found on sheet two of this data sheet.

This is an example of an Aethercomm standard product. Aethercomm designs and manufactures high performance, high power CW or pulsed SSPA's for commercial, military and satellite communications customer.

Aethercomm Inc. reserves the right to make changes without further notice. Aethercomm recommends that before these items herein are specified into a system or critical application that the performance characteristics be verified by contacting the factory.

SSPA 0.5-3.0-50

SSPA 0.5-3.0-50 Typical Performance @ 25°C

Freq (GHz)	Small Signal Gain (dB)	P3dB (dBm)	Current @ P3dB from a 50Vdc Supply (Amps)	DC Power from +50 Vdc Supply (Watts)	Power Added Efficiency (%)
0.50	36.9	48.9	6.94	347	22.4
0.75	39.5	50.7	8.26	413	28.5
1.00	37.3	49.2	9.74	487	17.1
1.25	30.8	48.0	9.22	461	13.7
1.50	33.5	49.0	9.12	456	17.4
1.75	36.9	48.5	10.0	500	14.4
2.00	39.0	50.2	10.5	525	20.0
2.25	37.8	49.9	10.1	505	19.4
2.50	36.6	49.1	9.83	491	16.5
2.75	34.8	49.5	9.33	467	19.1
3.00	33.1	48.8	9.61	481	15.8